

Silicon ESD Protector

Overvoltage Protection Device Circuit Protection Products PRODUCT: SESD0402P1BN-0450-090

DOCUMENT: SCD27764

REV LETTER: B

REV DATE: JULY 26, 2016

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Specification Status: Released

BENEFITS

- Silicon ESD device in an EIA-0402 size rectangular passive component SMT package
- Standard PCB assembly and rework processes
- Bi-directional operation allows placement on PCB without orientation constraint
- Appropriate for ESD protection in space-constrained portable electronics and mobile handsets
- Suitable for +5V operating voltage applications
- Helps protect electronic circuits against damage from Electrostatic Discharge (ESD) events
- Assist equipment to pass IEC61000-4-2, level 4 testing
- RoHS compliant and Halogen Free

FEATURES

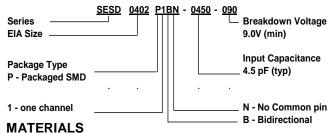
- Input capacitance 4.5pF (typ)
- Low leakage current 1.0µA (max)
- Low working reverse voltage 6.0V (max)
- ESD maximum rating per IEC61000-4-2 standard
 - ± 10kV contact discharge⁽¹⁾
 - o ± 16kV air discharge
- Capable of withstanding numerous ESD strikes
- Small package size: 1.10mm x 0.50mm (typ)
- Low package height: 0.50mm (typ)

APPLICATIONS

- Cellular phones and portable electronics
- Digital cameras and camcorders
- USB 2.0 and computer I/O ports
- Notebooks, set top boxes, motherboards
- Applications requiring high ESD performance

0201 SESD Circuit Diagram

PART NUMBERING



MATERIALS INFORMATION

RoHS Compliant ELV Compliant Halogen Free *







^{*} Halogen Free refers to: Br≤900ppm, Cl≤900ppm, Br+Cl≤1500ppm Terminal finish: 100% Matte Tin (Sn)

Device Characteristics @ T = 25°C	Min	Тур	Max	Unit
Input Capacitance @ V _r = 0V, f = 1MHz		4.5	5.5	pF
Working Reverse Voltage (peak) - V _{RWM}			6.0	V
Breakdown Voltage – $V_{br} @ I_t = 1 mA^{(2)}$	9.0	11.0		V
Leakage current @ V _{RWM} = 6.0V			1.0	μA
Clamping Voltage @ Ipp=2A, tp=(8/20µs)		±10.0	±12.0	V
ESD contact discharge per IEC61000-4-2 standard (1)			±10	kV
ESD air discharge per IEC61000-4-2 standard			±16	kV
Operating (T _{junction}) and Storage Temperature Range		-40 to +125		°c

^{(1) 10}kV @ 50 ± pulses under IEC61000-4-2; 8kV @ 1,000 pulses under IEC61000-4-2

⁽²⁾ V_{br} is measured at test current I_t



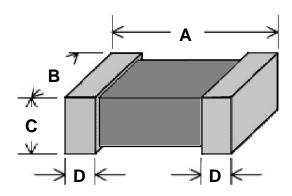
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DEVICE DIMENSIONS

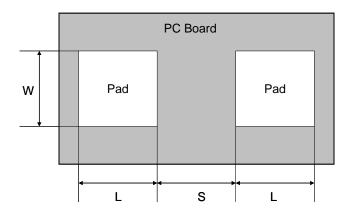


Drawings Not To Scale

Typical	А	В	С	D
mm	1.10 ± 0.1	0.50 ± 0.1	0.50 ± 0.1	0.25 ± 0.15
mils*	43.31 ± 4.0	19.69 ± 4.0	19.69 ± 4.0	9.84 ± 6.0

^{*} Round off approximation

RECOMMENDED LANDING PATTERN:



Typical	L	S	W	
mm	0.61 ± 0.05	0.52 ± 0.05	0.50 ± 0.05	
mils*	24.0 ± 2.0	21.0 ± 2.0	20.0 ± 2.0	

^{*} Round off approximation

- ullet Recommended solder thickness: 150 to 200 um
- Recommended rework procedure:
 - o Soldering iron tip temperature should be less than 350°C
 - Apply iron tip to solder for less than 5 seconds
 - Do not apply solder iron tip to the body of this product directly



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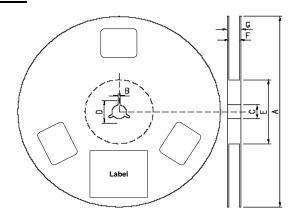
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PACKAGING

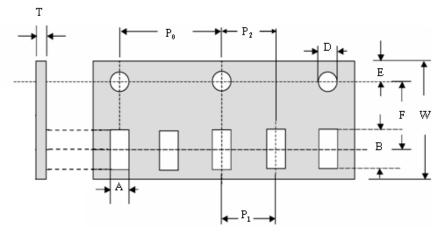
Packaging	Tape & Reel	Standard Box	
SESD0402P1BN-0450-090	10,000	50,000	

REEL DIMENSIONS



Dimension	Α	В	С	D	E	F	G
(mm)	178.0 ± 2.0	2.0 ± 0.5	13.0 ± 0.5	21.0 ± 0.8	62.0 ± 1.5	9.0 ± 0.5	13.0 ± 1.0

CARRIER TAPE DIMENSIONS



Dimension	Α	В	D	E	F	W
(mm)	0.58 ± 0.03	1.20 ± 0.03	1.55 ± 0.05	1.75 ± 0.05	3.5 ± 0.05	8.0 ± 0.1

Dimension	mension P ₀		P ₂	Т	
(mm)	4.0 ± 0.1	2.0 ± 0.05	2.0 ± 0.05	0.60 ± 0.03	



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FIGURE 1: TYPICAL IV CURVE

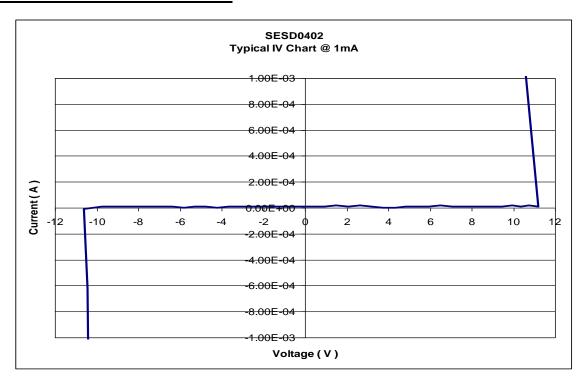
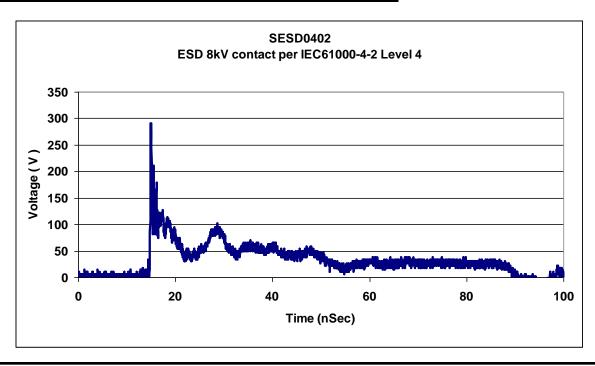


FIGURE 2: ESD CLAMPING VOLTAGE - 8kV Contact





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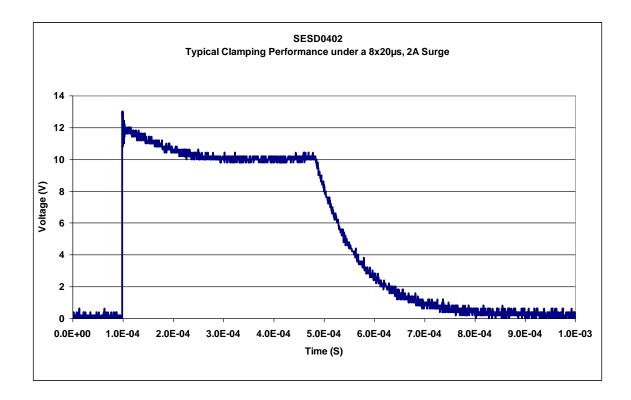
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FIGURE 3: ESD CLAMPING VOLTAGE - 8x20µs, 2A Surge



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